

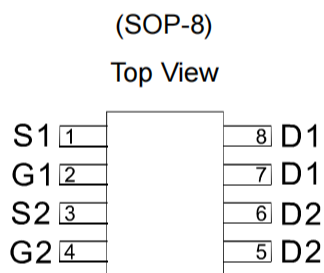
GENERAL FEATURES

- $R_{DS(ON)} \leq 35 \text{ m}\Omega @ V_{GS}=10\text{V}$
- $R_{DS(ON)} \leq 45 \text{ m}\Omega @ V_{GS}=4.5\text{V}$
- Super high density cell design for extremely low $R_{DS(ON)}$
- Exceptional on-resistance and maximum DC current capability

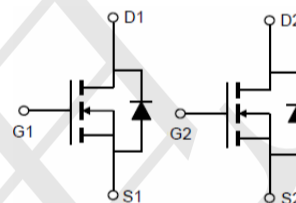
Application

- Power Management in Note book
- Portable Equipment
- Battery Powered System
- DC/DC Converter
- Load Switch
- DSC
- LCD Display inverter

Package and Pin Configuration

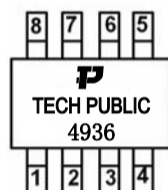


Circuit diagram



Schematic diagram

Marking:



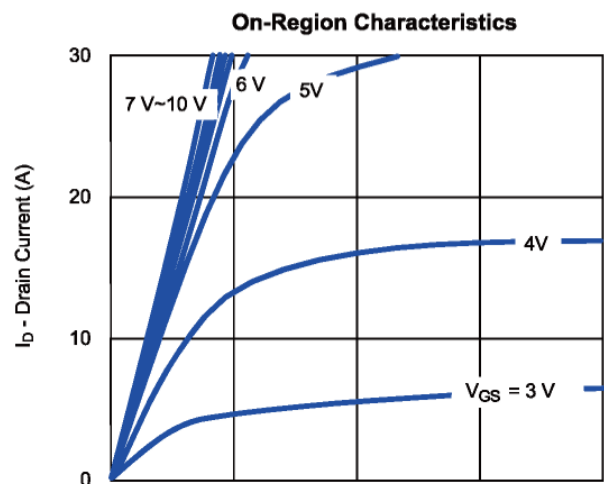
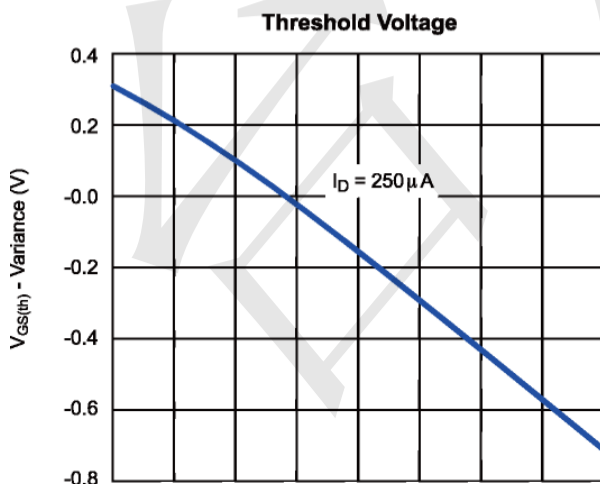
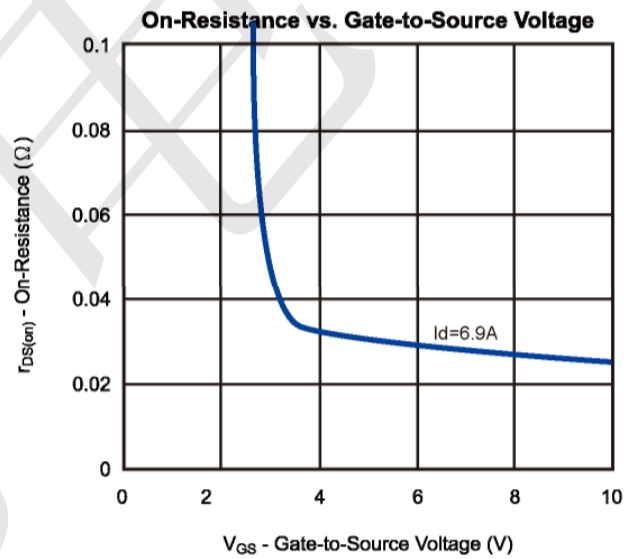
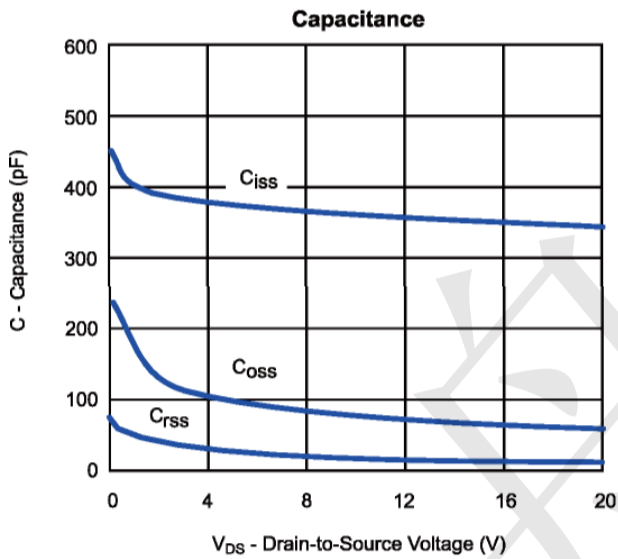
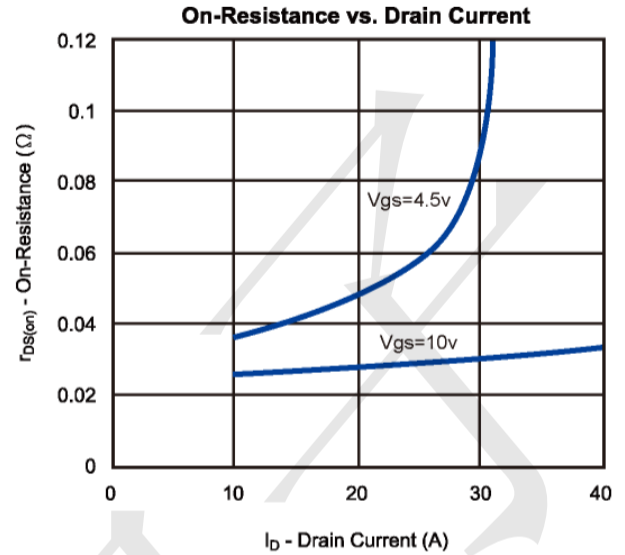
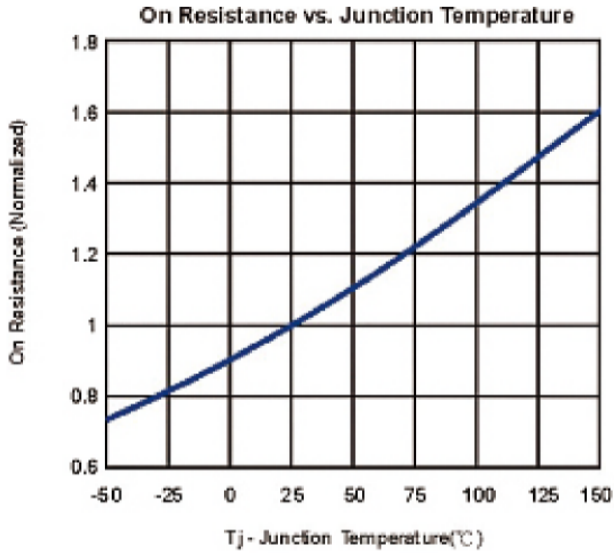
Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

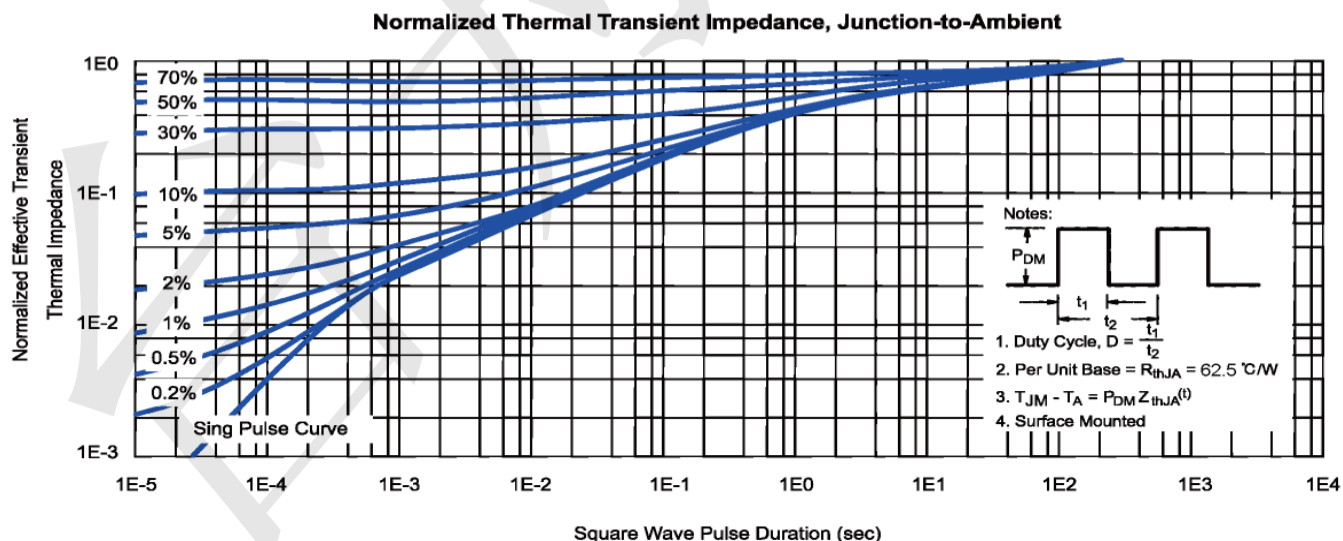
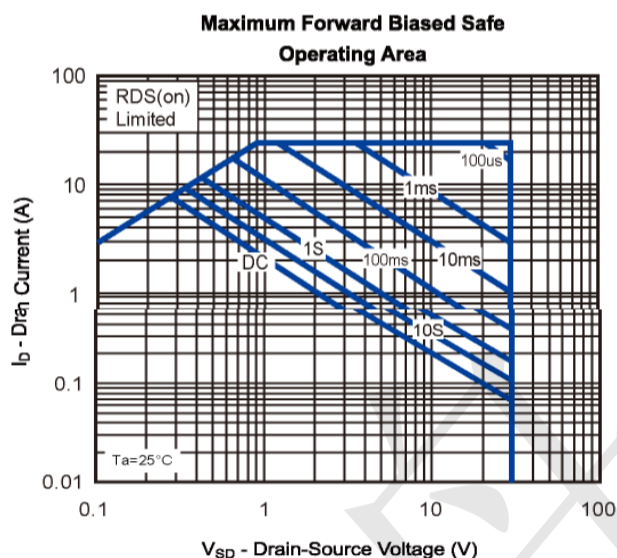
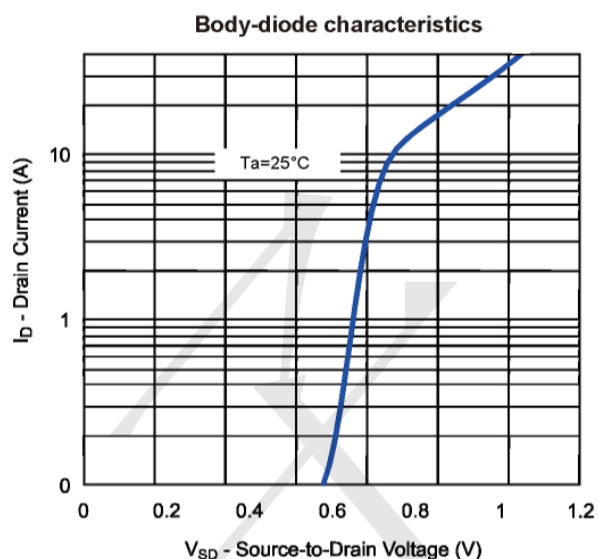
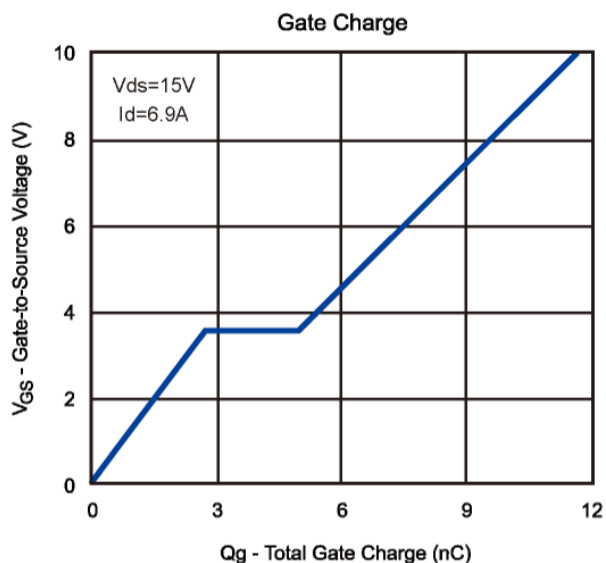
Parameter	Symbol	Maximum Ratings	Unit
Drain-Source Voltage	V_{DS}	30	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	I_D	$T_A=25^\circ\text{C}$	A
		$T_A=70^\circ\text{C}$	
Pulsed Drain Current	I_{DM}	24	A
Maximum Power Dissipation	P_D	$T_A=25^\circ\text{C}$	W
		$T_A=70^\circ\text{C}$	
Operating Junction Temperature	T_J	-55 to 150	$^\circ\text{C}$
Thermal Resistance-Junction to Ambient*	$R_{\theta JA}$	62.5	$^\circ\text{C/W}$

Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

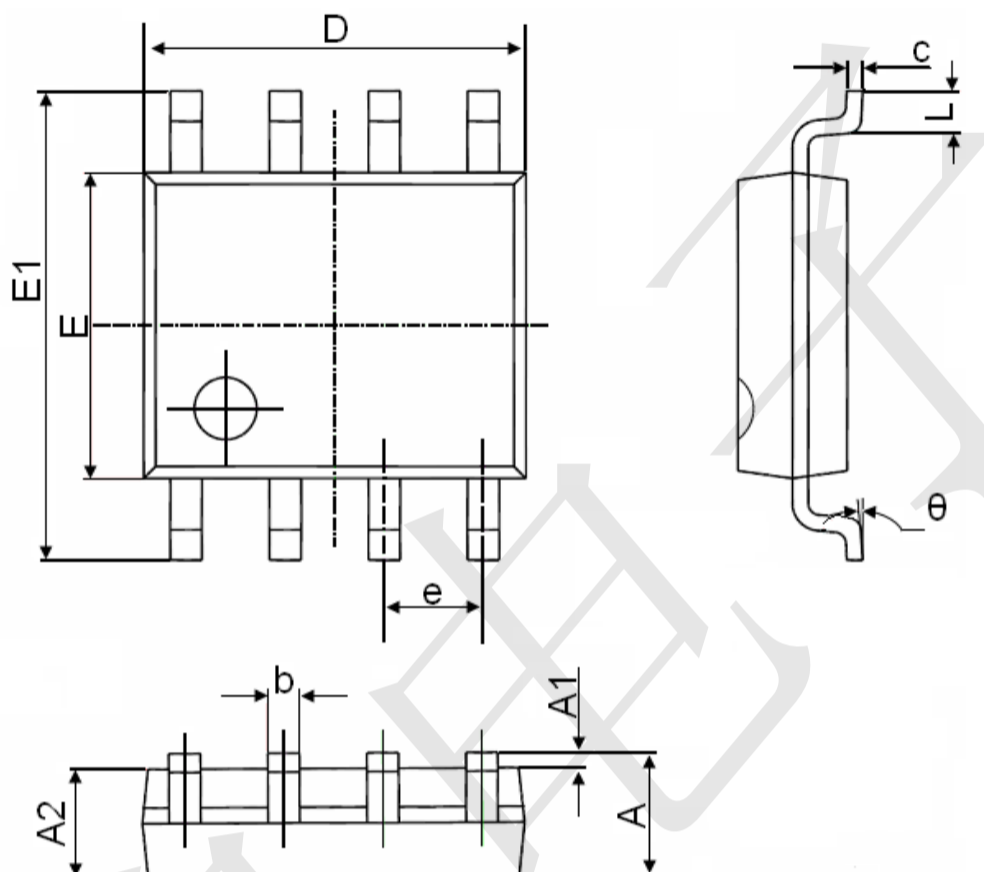
Symbol	Parameter	Limit	Min	Typ	Max	Unit
STATIC						
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	$V_{GS}=0V, I_D=250\mu A$	30			V
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}, I_D=250\mu A$	1		3	V
I_{GSS}	Gate Leakage Current	$V_{DS}=0V, V_{GS}=\pm 20V$			± 100	nA
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS}=30V, V_{GS}=0V$			1	μA
$R_{DS(on)}$	Drain-Source On-Resistance	$V_{GS}=10V, I_D=6.9A$		18	35	$m\Omega$
		$V_{GS}=4.5V, I_D=5.8A$		24	45	
V_{SD}	Diode Forward Voltage	$I_S=1.7A, V_{GS}=0V$		0.75	1.2	V
DYNAMIC						
Q_g	Total Gate Charge	$V_{DS}=15V, V_{GS}=10V, I_D=6.9A$		11.5		nC
Q_{gs}	Gate-Source Charge			2.7		
Q_{gd}	Gate-Drain Charge			2.3		
C_{iss}	Input Capacitance	$V_{DS}=15V, V_{GS}=0V, f=1MHz$		350		pF
C_{oss}	Output Capacitance			65		
C_{rss}	Reverse Transfer Capacitance			16		
$t_{d(on)}$	Turn-On Delay Time	$V_{DD}=15V, R_L=15\Omega$ $I_D=1A, V_{GEN}=10V$ $R_G=6\Omega$		9		ns
t_r	Turn-On Rise Time			10		
$t_{d(off)}$	Turn-Off Delay Time			32		
t_f	Turn-Off Fall Time			3.5		

Typical Electrical and Thermal Characteristics





SOP-8 Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270(BSC)		0.050(BSC)	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°